NSN 5961-01-180-2896

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-180-2896 **Inclosure Material:** Glass **Overall Length:** 0.170 inches **Terminal Length:** 0.975 inches **Overall Diameter:** Between 0.068 inches and 0.076 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Terminal surfaces silver **Precious Material:** Silver **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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